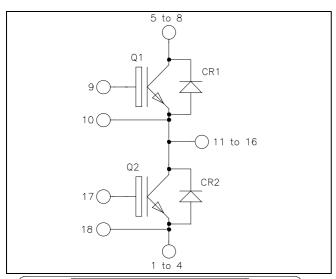
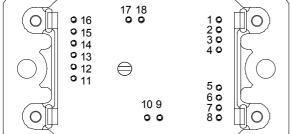


Phase leg NPT IGBT Power Module

 $V_{CES} = 1200V$ $I_C = 100A$ @ Tc = 80°C





Pins 1/2/3/4 ; 5/6/7/8 ; 11/12/13/14/15/16 must be shorted together

Application

- Welding converters
- Switched Mode Power Supplies
- Uninterruptible Power Supplies
- Motor control

Features

- Non Punch Through (NPT) Fast IGBT
 - Low voltage drop
 - Low tail current
 - Switching frequency up to 50 kHz
 - Soft recovery parallel diodes
 - Low diode VF
 - Low leakage current
 - RBSOA and SCSOA rated
- Kelvin emitter for easy drive
- Very low stray inductance
- High level of integration

Benefits

- Outstanding performance at high frequency operation
- Stable temperature behavior
- Very rugged
- Direct mounting to heatsink (isolated package)
- Low junction to case thermal resistance
- Easy paralleling due to positive T_C of V_{CEsat}
- RoHS Compliant

All ratings @ $T_i = 25$ °C unless otherwise specified

Absolute maximum ratings

Symbol	Parameter		Max ratings	Unit
V_{CES}	Collector - Emitter Breakdown Voltage		1200	V
Ţ	Continuous Collector Current	$T_c = 25^{\circ}C$	135	
I_{C}	Continuous Conector Current	$T_c = 80$ °C	100	A
I_{CM}	Pulsed Collector Current	$T_c = 25^{\circ}C$	300	
V_{GE}	Gate – Emitter Voltage		±20	V
P_{D}	Maximum Power Dissipation	$T_c = 25^{\circ}C$	568	W
RBSOA	Reverse Bias Safe Operating Area	$T_{j} = 150^{\circ}C$	200A @ 1200V	

CAUTION: These Devices are sensitive to Electrostatic Discharge. Proper Handling Procedures Should Be Followed. See application note APT0502 on www.microsemi.com



Electrical Characteristics

Symbol	Characteristic	Test Conditions		Min	Тур	Max	Unit
I_{CES}	Zero Gate Voltage Collector Current	$V_{GE} = 0V, V_{CE} = 1200V$				250	μA
V _{CE(sat)}	Collector Emitter Saturation Voltage	$V_{GE} = 15V$	$T_j = 25$ °C		3.2	3.7	V
		$I_C = 100A$ $T_j = 125^{\circ}C$		3.9		v	
$V_{GE(th)}$	Gate Threshold Voltage	$V_{GE} = V_{CE}$, $I_C = 4mA$		4.5	5.5	6.5	V
I_{GES}	Gate – Emitter Leakage Current	$V_{GE} = 20V, V_{CE} = 0V$				600	nA

Dynamic Characteristics

·	Characteristic	Test Condition	Test Conditions		Typ	Max	Unit
Cies	Input Capacitance	$V_{GE} = 0V$	$V_{GE} = 0V$ $V_{CE} = 25V$		6.5		nF
Coes	Output Capacitance				1		
C_{res}	Reverse Transfer Capacitance	f = 1MHz			0.5		
Q_{G}	Gate charge	$V_{GE} = \pm 15V ; V$ $I_{C} = 100A$	$V_{GE} = \pm 15V ; V_{CE} = 600V$ $I_{C} = 100A$		1.1		μС
$T_{d(on)}$	Turn-on Delay Time	Inductive Switch	ching (25°C)		120		
$T_{\rm r}$	Rise Time	$V_{GE} = \pm 15V$			50		
$T_{d(off)}$	Turn-off Delay Time	$I_{\rm C} = 100 A$	$V_{\text{Bus}} = 600V$ $I_{\text{G}} = 100 \text{ A}$		310		ns
T_{f}	Fall Time	$R_G = 5.6\Omega$		20			
$T_{d(on)}$	Turn-on Delay Time	Inductive Switching (125°C) $V_{GE} = \pm 15V$			130		ns
$T_{\rm r}$	Rise Time				60		
$T_{d(off)}$	Turn-off Delay Time	$V_{Bus} = 600 V$ $I_{C} = 100 A$	$V_{\text{Bus}} = 600V$ $I_{\text{Bus}} = 100 \text{ A}$		360		
T_{f}	Fall Time	$R_G = 5.6\Omega$			30		
Eon	Turn-on Switching Energy	$V_{GE} = \pm 15V$ $V_{Bus} = 600V$	$T_j = 125$ °C		12		I
E_{off}	Turn-off Switching Energy	$I_C = 100A$ $R_G = 5.6\Omega$	$T_j = 125$ °C		5		mJ
I_{sc}	Short Circuit data	$V_{GE} \le 15V$; $V_{Bus} = 900V$ $t_p \le 10 \mu s$; $T_i = 125 ^{\circ}C$			650		A
R_{thJC}	Junction to Case Thermal Resistance					0.19	°C/W

Reverse diode ratings and characteristics

Symbol	Characteristic	Test Conditions		Min	Тур	Max	Unit
V_{RRM}	Maximum Peak Repetitive Reverse Voltage			1200			V
I_{RM}	Maximum Reverse Leakage Current	$V_R = 1200V$				250	μΑ
I_{F}	DC Forward Current		Tc = 80°C		100		A
	Diode Forward Voltage	$I_{\rm F} = 100A$			2.4	3	V
$V_{\rm F}$		$I_F = 150A$			2.7		
		$I_{\rm F} = 100A$	$T_j = 125$ °C		1.8		
4	Reverse Recovery Time		$T_j = 25^{\circ}C$		385		
t_{rr}		$I_F = 100A$ $V_R = 800V$ $T_j = 125^{\circ}C$			480		ns
Q _{rr}	Reverse Recovery Charge	$di/dt = 200 A/\mu s$	$T_j = 25$ °C		1055		nC
		$T_{\rm j} = 125^{\circ}$			5240		iiC
R_{thJC}	Junction to Case Thermal Resistance					0.55	°C/W

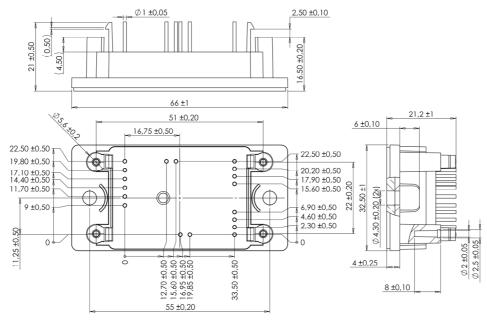
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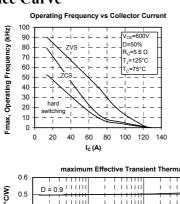
Thermal and package characteristics

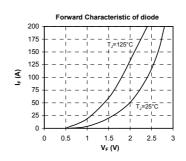
Symbol	Characteristic		Min	Тур	Max	Unit	
V_{ISOL}	RMS Isolation Voltage, any terminal to case t = 1 min, 50/60Hz			4000			V
T_{J}	Operating junction temperature range			-40		150	
T_{STG}	Storage Temperature Range			-40		125	°C
$T_{\rm C}$	Operating Case Temperature			-40		100	
Torque	Mounting torque	To heatsink	M4	2		3	N.m
Wt	Package Weight					75	g

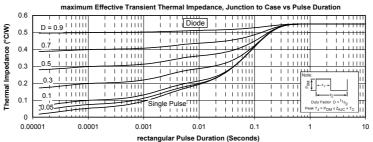
SP2 Package outline (dimensions in mm)



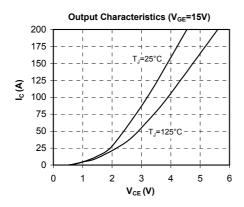
Typical Performance Curve

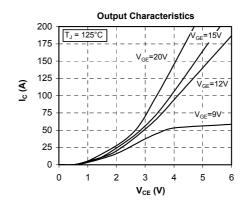


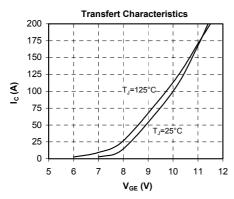


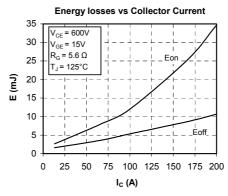


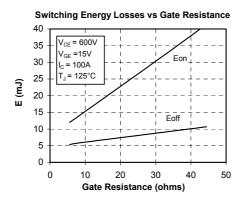


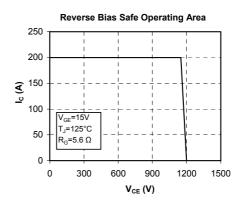


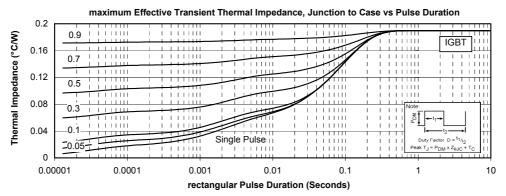












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